

BC817W-QF Datasheet



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DiGi Electronics Part Number BC817W-QF-DG

Manufacturer Nexperia USA Inc.

Manufacturer Product Number BC817W-QF

Description BC817W-Q/SOT323/SC-70

Detailed Description Bipolar (BJT) Transistor NPN 45 V 500 mA 100MHz 2

00 mW Surface Mount SOT-323



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Purchase and inquiry

Manufacturer Product Number:	Manufacturer:
BC817W-QF	Nexperia USA Inc.
Series:	Product Status:
	Active
Transistor Type:	Current - Collector (Ic) (Max):
NPN	500 mA
Voltage - Collector Emitter Breakdown (Max):	Vce Saturation (Max) @ lb, lc:
45 V	700mV @ 50mA, 500mA
Current - Collector Cutoff (Max):	DC Current Gain (hFE) (Min) @ Ic, Vce:
100nA (ICBO)	100 @ 100mA, 1V
Power - Max:	Frequency - Transition:
200 mW	100MHz
Operating Temperature:	Grade:
150°C (TJ)	Automotive
Qualification:	Mounting Type:
AEC-Q101	Surface Mount
Package / Case:	Supplier Device Package:
SC-70, SOT-323	SOT-323
Base Product Number:	
BC817	

Environmental & Export classification

RoHS Status:	REACH Status:
ROHS3 Compliant	REACH Unaffected
ECCN:	HTSUS:
EAR99	8541.21.0095



45 V, 500 mA NPN general-purpose transistors

Rev. 1 — 8 June 2021

Product data sheet

1. General description

NPN general-purpose transistor in a very small SOT323 (SC70) Surface-Mounted Device (SMD) plastic package.

Table 1. Product overview

Type number	Package	PNP complement		
	Nexperia	JEDEC	JEITA	
BC817W-Q	SOT323	-	SC-70	BC807W-Q
BC817-16W-Q				BC807-16W-Q
BC817-25W-Q				BC807-25W-Q
BC817-40W-Q				BC807-40W-Q

2. Features and benefits

- High current
- Three current gain selections
- Qualified according to AEC-Q101 and recommended for use in automotive applications

3. Applications

· General-purpose switching and amplification

4. Quick reference data

Table 2. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V_{CEO}	collector-emitter voltage	open base; T _{amb} = 25 °C		-	-	45	V
I _C	collector current	T _{amb} = 25 °C	T _{amb} = 25 °C		-	500	mA
I _{CM}	peak collector current	single pulse; t _p ≤ 1 ms; T _{amb} = 25 °C		-	-	1	Α
h _{FE}	DC current gain					•	
	BC817W-Q	V _{CE} = 1 V; I _C = 100 mA T _{amb} = 25 °C	[1]	100	-	600	
	BC817-16W-Q		[1]	100	-	250	
	BC817-25W-Q		[1]	160	-	400	
	BC817-40W-Q		[1]	250	-	600	

[1] pulsed; $t_p \le 300 \ \mu s$; $\delta \le 0.02$



5. Pinning information

Table 3. Pinning

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	В	base	<u></u> 3	С
2	E	emitter		
3	С	collector		B—
				É
				sym123
			1 🗀 🗀 2	

6. Ordering information

Table 4. Ordering information

Type number	Package		
	Name	Description	Version
BC817W-Q	SC-70	Plastic surface-mounted package; 3 leads	SOT323
BC817-16W-Q			
BC817-25W-Q	1		
BC817-40W-Q			

7. Marking

Table 5. Marking

Type number	Marking code[1]
BC817W-Q	6D%
BC817-16W-Q	6A%
BC817-25W-Q	6B%
BC817-40W-Q	6C%

[1] % = placeholder for manufacturing site code

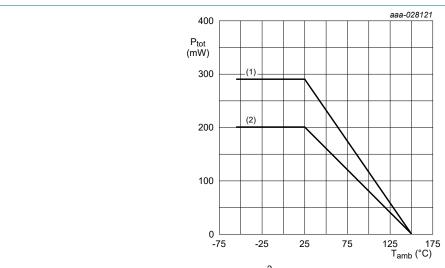
8. Limiting values

Table 6. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V _{CBO}	collector-base voltage	open emitter; T _{amb} = 25 °C	open emitter; T _{amb} = 25 °C			V
V _{CEO}	collector-emitter voltage	open base; T _{amb} = 25 °C		-	45	V
V _{EBO}	emitter-base voltage	open collector; T _{amb} = 25 °C		-	5	V
Ic	collector current	T _{amb} = 25 °C		-	500	mA
I _{CM}	peak collector current	single pulse; t _p ≤ 1 ms; T _{amb} = 25 °	single pulse; t _p ≤ 1 ms; T _{amb} = 25 °C			Α
I _{BM}	peak base current	single pulse; t _p ≤ 1 ms; T _{amb} = 25 °	single pulse; t _p ≤ 1 ms; T _{amb} = 25 °C			mA
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[1] [2]	-	200	mW
			[3] [2]	-	290	mW
T _j	junction temperature					°C
T _{amb}	ambient temperature			-65	150	°C
T _{stg}	storage temperature			-65	150	°C

- [1] Device mounted on an FR4 Printed-Circuit-Board (PCB), single-sided copper, tin-plated and standard footprint.
- [2] Valid for all available selection groups.
- [3] Device mounted on an FR4 PCB, single-sided copper, tin-plated; mounting pad for collector 1 cm².



- (1) FFR4 PCB, single-sided copper; 1 cm²
- (2) FR4 PCB, single-sided copper; standard footprint

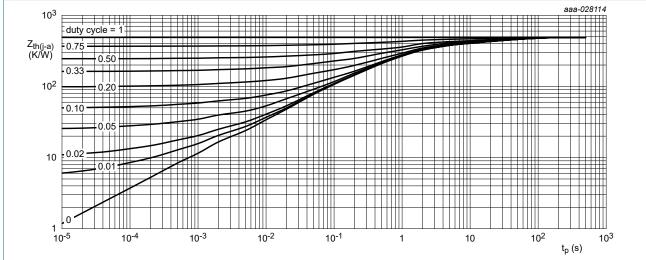
Fig. 1. Power derating curves

9. Thermal characteristics

Table 7. Thermal characteristics

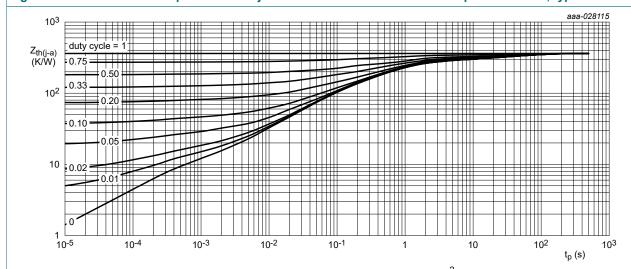
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R _{th(j-a)}	thermal resistance from junction to ambient	in free air	[1] [2]	-	-	625	K/W
			[3] [2]	-	-	431	K/W

- [1] Device mounted on an FR4 PCB; single-sided copper; tin-plated and standard footprint.
- [2] Valid for all available selection groups.
- [3] Device mounted on an FR4 PCB, single-sided copper, tin-plated; monting pad for collector 1 cm².



FR4 PCB, single-sided, tin-plated and standard footprint

Fig. 2. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values



FR4 PCB, single-sided copper, tin-plated; mounting pad for collector 1 cm².

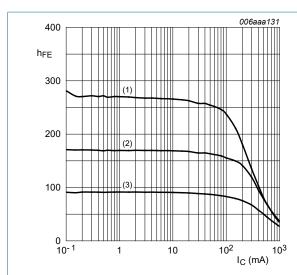
Fig. 3. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

10. Characteristics

Table 8. Characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
$V_{(BR)CBO}$	collector-base breakdown voltage	I _C = 100 μA; I _E = 0 A; T _{amb} = 25 °C		50	-	-	V
V _{(BR)CEO}	collector-emitter breakdown voltage	I _C = 10 mA; I _E = 0 A; T _{amb} = 25 °C	$I_C = 10 \text{ mA}; I_E = 0 \text{ A}; T_{amb} = 25 \text{ °C}$		-	-	V
V _{(BR)EBO}	emitter-base breakdown voltage	I _E = 100 μA; I _C = 0 A; T _{amb} = 25 °C	$I_E = 100 \mu A; I_C = 0 A; T_{amb} = 25 °C$ 5		-	-	V
I _{CBO}	collector-base	V _{CB} = 20 V; I _E = 0 A; T _{amb} = 25 °C		-	-	100	nA
	cut-off current	V _{CB} = 20 V; I _E = 0 A; T _j = 150 °C		-	-	5	μA
I _{EBO}	emitter-base cut-off current	V _{EB} = 5 V; I _C = 0 A; T _{amb} = 25 °C		-	-	100	nA
h _{FE}	DC current gain						'
BC817W-Q BC817-16W-Q	V _{CE} = 1 V; I _C = 100 mA; T _{amb} = 25 °C	[1]	100	-	600		
	BC817-16W-Q		[1]	100	-	250	
	BC817-25W-Q		[1]	160	-	400	
	BC817-40W-Q		[1]	250	-	600	
h _{FE}	DC current gain	V _{CE} = 1 V; I _C = 500 mA; T _{amb} = 25 °C	[1]	40	-	-	
V _{CEsat}	collector-emitter saturation voltage	$I_C = 500 \text{ mA}; I_B = 50 \text{ mA}; T_{amb} = 25 \text{ °C}$	[1]	-	-	700	mV
V_{BE}	base-emitter voltage	V _{CE} = 1 V; I _C = 500 mA; T _{amb} = 25 °C	[1] [2]	-	-	1.2	V
f _T	transition frequency	V _{CE} = 5 V; I _C = 10 mA; f = 100 MHz; T _{amb} = 25 °C		100	-	-	MHz
C _c	collector capacitance	$V_{CB} = 10 \text{ V}; I_{E} = i_{e} = 0 \text{ A}; f = 1 \text{ MHz};$ $T_{amb} = 25 \text{ °C}$		-	3	-	pF
		The state of the s				- 1	

 $[\]begin{array}{ll} [1] & \text{pulsed; } t_p \leq 300 \ \mu\text{s; } \delta \leq 0.02 \\ [2] & V_{BE} \ \text{decreases by about 2 mV/K with increasing temperature.} \end{array}$



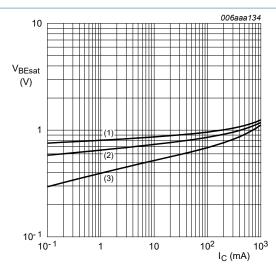
$$V_{CE} = 1 V$$

(1)
$$T_{amb} = 150 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = -55 \, ^{\circ}C$$

Fig. 4. BC817-16W-Q: DC current gain as a function of collector current; typical values

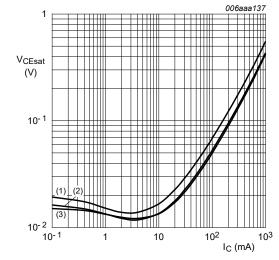


(1)
$$T_{amb} = -55 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = 150 \, ^{\circ}C$$

Fig. 5. BC817-16W-Q: Base-emitter saturation voltage as a function of collector current; typical values



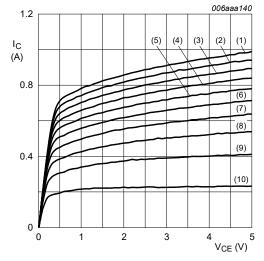
IC/IB = 10

(1)
$$T_{amb} = 150 \, ^{\circ}C$$

(2)
$$T_{amb}$$
 = 25 °C

(3)
$$T_{amb} = -55 \, ^{\circ}C$$

Fig. 6. BC817-16W-Q: Collector-emitter saturation voltage as a function of collector current; typical values



T_{amb} = 25 °C

 $(1) I_B = 16.0 \text{ mA}$

 $(2) I_B = 14.4 \text{ mA}$

(3) $I_B = 12.8 \text{ mA}$

(4) $I_B = 11.2 \text{ mA}$

(5) $I_B = 9.6 \text{ mA}$

(6) $I_B = 8.0 \text{ mA}$

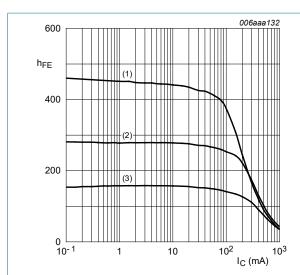
 $(7) I_B = 6.4 \text{ mA}$

(8) $I_B = 4.8 \text{ mA}$

(9) $I_B = 3.2 \text{ mA}$

 $(10) I_B = 1.6 \text{ mA}$

Fig. 7. BC817-16W-Q: Collector current as a function of collector-emitter voltage; typical values



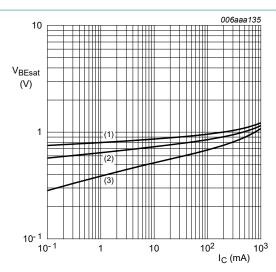
$$V_{CE} = 1 V$$

(1)
$$T_{amb} = 150 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = -55 \, ^{\circ}C$$

Fig. 8. BC817-25W-Q: DC current gain as a function of collector current; typical values



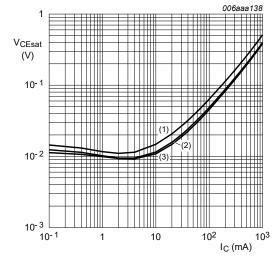
$$IC/IB = 10$$

(1)
$$T_{amb} = -55 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = 150 \, ^{\circ}C$$

Fig. 9. BC817-25W-Q: Base-emitter saturation voltage as a function of collector current; typical values

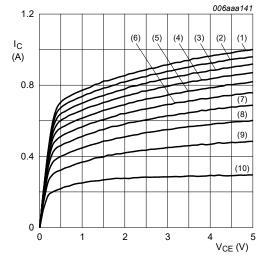


IC/IB = 10

(2)
$$T_{amb}$$
 = 25 °C

(3)
$$T_{amb} = -55 \, ^{\circ}C$$

Fig. 10. BC817-25W-Q: Collector-emitter saturation voltage as a function of collector current; typical values



(1)
$$I_B = 13.0 \text{ mA}$$

(2)
$$I_B = 11.7 \text{ mA}$$

$$(3) I_B = 10.4 \text{ mA}$$

(4)
$$I_B = 9.1 \text{ mA}$$

$$(5) I_B = 7.8 \text{ mA}$$

(6)
$$I_B = 6.5 \text{ mA}$$

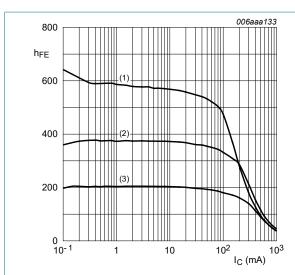
$$(7) I_B = 5.2 \text{ mA}$$

(8)
$$I_B = 3.9 \text{ mA}$$

(9)
$$I_B = 2.6 \text{ mA}$$

$$(10) I_B = 1.3 \text{ mA}$$

Fig. 11. BC817-25W-Q: Collector current as a function of collector-emitter voltage; typical values



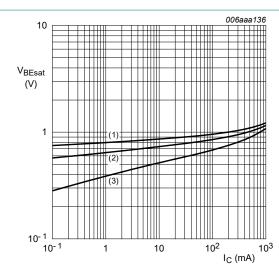
$$V_{CE} = 1 V$$

(1)
$$T_{amb} = 150 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = -55$$
 °C

Fig. 12. BC817-40W-Q: DC current gain as a function of Fig. 13. BC817-40W-Q: Base-emitter saturation voltage collector current; typical values



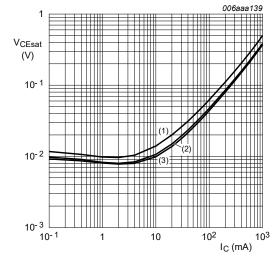
$$IC/IB = 10$$

(1)
$$T_{amb} = -55 \, ^{\circ}C$$

(2)
$$T_{amb}$$
 = 25 °C

(3)
$$T_{amb} = 150 \, ^{\circ}C$$

as a function of collector current; typical values

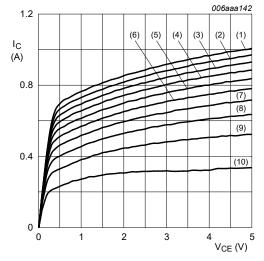


IC/IB = 10

(2)
$$T_{amb}$$
 = 25 °C

(3)
$$T_{amb} = -55 \, ^{\circ}C$$

Fig. 14. BC817-40W-Q: Collector-emitter saturation voltage as a function of collector current; typical values



(1)
$$I_B = 12.0 \text{ mA}$$

(2)
$$I_B = 10.8 \text{ mA}$$

$$(3) I_B = 9.6 \text{ mA}$$

$$(4) I_B = 8.4 \text{ mA}$$

$$(5) I_B = 7.2 \text{ mA}$$

(6)
$$I_B = 6.0 \text{ mA}$$

$$(7) I_B = 4.8 \text{ mA}$$

(8)
$$I_B = 3.6 \text{ mA}$$

(9)
$$I_B = 2.4 \text{ mA}$$

$$(10) I_B = 1.2 mA$$

Fig. 15. BC817-40W-Q: Collector current as a function of collector-emitter voltage; typical values

45 V, 500 mA NPN general-purpose transistors

11. Test information

11.1. Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101 - Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

12. Package outline

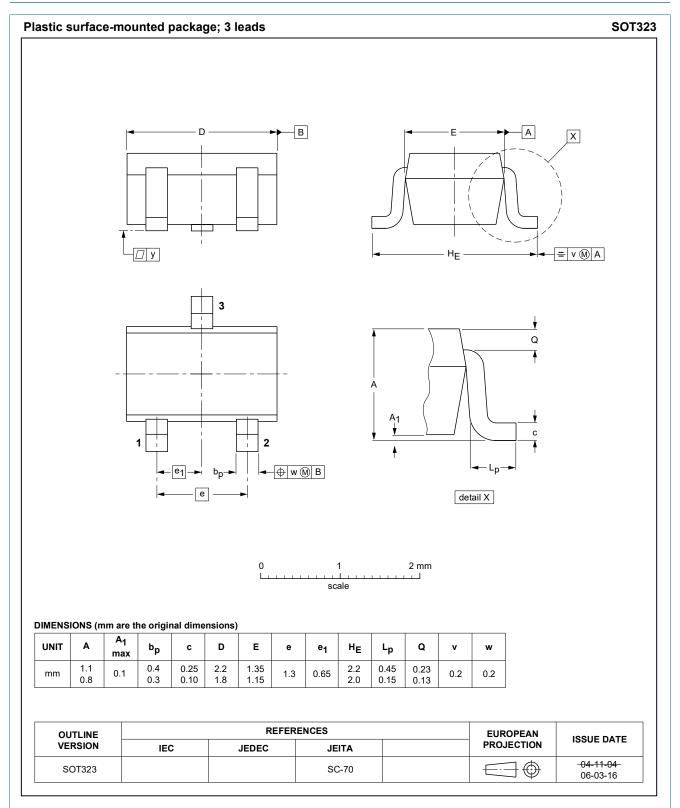
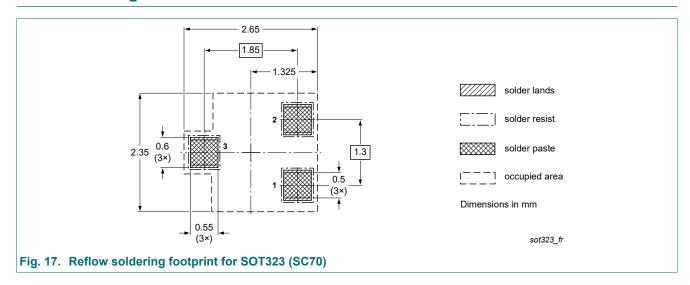
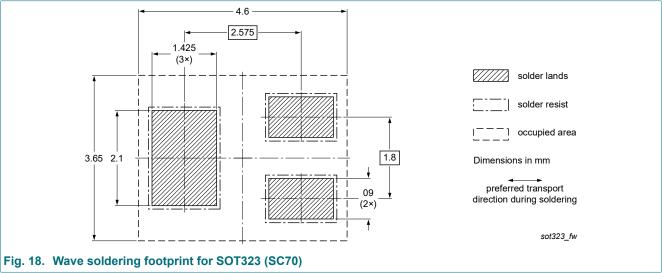


Fig. 16. Package outline SOT323 (SC70)

13. Soldering





45 V, 500 mA NPN general-purpose transistors

14. Revision history

Table 9. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
BC817W-Q_SER v.1	20210608	Product data sheet	-	-

15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
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